

# 74LVC86A

Quad 2-input EXCLUSIVE-OR gate

Rev. 05.00 — 15 May 2006

Product data sheet

## 1. General description

The 74LVC86A provides four 2-input EXCLUSIVE-OR functions. It is a high-performance, low power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V applications.

## 2. Features

- 5 V tolerant inputs for interlacing with 5 V logic
- Supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Complies with JEDEC standard JESD8-B / JESD36
- ESD protection:
  - ◆ HBM JESD22-A114-C exceeds 2000 V
  - ◆ CDM JESD22-C101-C exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to 125 °C

## 3. Ordering information

Table 1: Ordering information

| Type number | Package           |          |   |          |
|-------------|-------------------|----------|---|----------|
|             | Temperature range | Name     | Description   | Version  |
| 74LVC86AD   | -40 °C to +125 °C | SO14     | plastic small outline package; 14 leads;<br>body width 3.9 mm   | SOT108-1 |
| 74LVC86ADB  | -40 °C to +125 °C | SSOP14   | plastic shrink small outline package; 14 leads;<br>body width 5.3 mm  | SOT337-1 |
| 74LVC86APW  | -40 °C to +125 °C | TSSOP14  | plastic thin shrink small outline package; 14 leads;<br>body width 4.4 mm   | SOT402-1 |
| 74LVC86ABQ  | -40 °C to +125 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals;<br>body 2.5 × 3 × 0.85 mm | SOT762-1 |

**PHILIPS**

## 4. Functional diagram

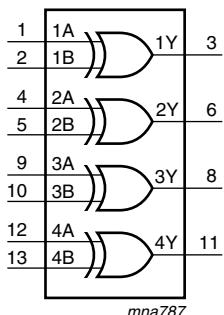


Fig 1. Logic diagram

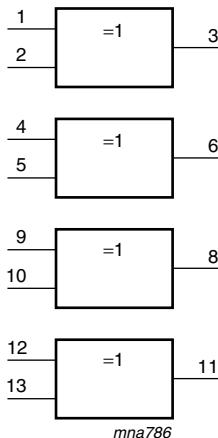


Fig 2. IEC logic symbol

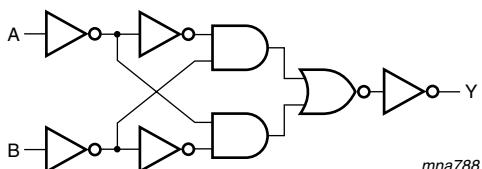


Fig 3. Logic diagram for one gate

## 5. Pinning information

### 5.1 Pinning

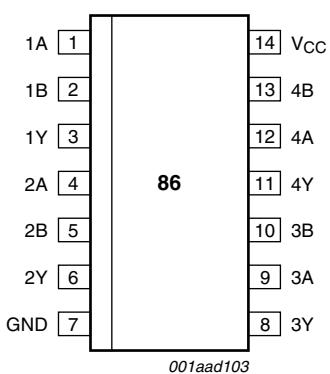
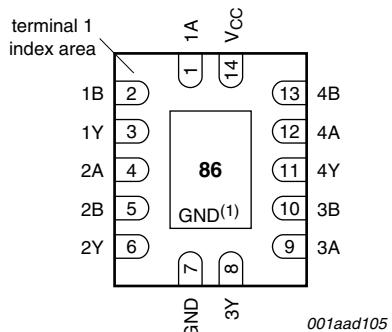


Fig 4. Pin configuration for SO14 and (T)SSOP14



- (1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig 5. Pin configuration for DHVQFN14

## 5.2 Pin description

**Table 2:** Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| 1A              | 1   | data input     |
| 1B              | 2   | data input     |
| 1Y              | 3   | data output    |
| 2A              | 4   | data input     |
| 2B              | 5   | data input     |
| 2Y              | 6   | data output    |
| GND             | 7   | ground (0 V)   |
| 3Y              | 8   | data output    |
| 3A              | 9   | data input     |
| 3B              | 10  | data input     |
| 4Y              | 11  | data output    |
| 4A              | 12  | data input     |
| 4B              | 13  | data input     |
| V <sub>CC</sub> | 14  | supply voltage |

## 6. Functional description

**Table 3:** Functional table<sup>[1]</sup>

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | L  | L      |
| L     | H  | H      |
| H     | L  | H      |
| H     | H  | L      |

[1] H = HIGH voltage level

L = LOW voltage level.

## 7. Limiting values

**Table 4: Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   | Min      | Max                   | Unit |
|------------------|-------------------------|--|----------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |  | -0.5     | +6.5                  | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0                                     | -        | -50                   | mA   |
| V <sub>I</sub>   | input voltage           |  | [1] -0.5 | +6.5                  | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> > V <sub>CC</sub> or V <sub>O</sub> < 0 | -        | ±50                   | mA   |
| V <sub>O</sub>   | output voltage          |  | [1] -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = 0 to V <sub>CC</sub>                  | -        | ±50                   | mA   |
| I <sub>CC</sub>  | supply current          |  | -        | +100                  | mA   |
| I <sub>GND</sub> | ground current          |  | -        | -100                  | mA   |
| T <sub>stg</sub> | storage temperature     |  | -65      | +150                  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C                   | [2] -    | 500                   | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 packages: above 70 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.

For (T)SSOP14 packages: above 60 °C the value of P<sub>tot</sub> derates linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60 °C the value of P<sub>tot</sub> derates linearly with 4.5 mW/K.

## 8. Recommended operating conditions

**Table 5: Recommended operating conditions**

| Symbol           | Parameter                           | Conditions                        | Min | Typ | Max             | Unit |
|------------------|-------------------------------------|-----------------------------------|-----|-----|-----------------|------|
| V <sub>CC</sub>  | supply voltage                      |                                   | 1.2 | -   | 3.6             | V    |
| V <sub>I</sub>   | input voltage                       |                                   | 0   | -   | 5.5             | V    |
| V <sub>O</sub>   | output voltage                      |                                   | 0   | -   | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature                 | in free air                       | -40 | -   | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 1.65 V to 2.7 V | 0   | -   | 20              | ns/V |
|                  |                                     | V <sub>CC</sub> = 2.7 V to 3.6 V  | 0   | -   | 10              | ns/V |

## 9. Static characteristics

**Table 6: Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                               | Conditions   | Min                    | Typ <sup>[1]</sup> | Max                    | Unit |
|--|---|--|------------------------|--------------------|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +85 °C</b>  |   |  |                        |                    |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage                | V <sub>CC</sub> = 1.2 V  | 1.08                   | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.65 × V <sub>CC</sub> | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                    | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2.0                    | -                  | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage                 | V <sub>CC</sub> = 1.2 V  | -                      | -                  | 0.12                   | V    |
|  |   | V <sub>CC</sub> = 1.65 V to 1.95 V   | -                      | -                  | 0.35 × V <sub>CC</sub> | V    |
|  |   | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                      | -                  | 0.7                    | V    |
|  |   | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                      | -                  | 0.8                    | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage               | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                        |                    |                        |      |
|  |   | I <sub>O</sub> = -100 µA; V <sub>CC</sub> = 1.65 V to 3.6 V                                    | V <sub>CC</sub> - 0.2  | -                  | -                      | V    |
|  |   | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V   | V <sub>CC</sub> - 0.45 | -                  | -                      | V    |
|  |   | I <sub>O</sub> = -8 mA; V <sub>CC</sub> = 2.3 V  | V <sub>CC</sub> - 0.5  | -                  | -                      | V    |
|  |   | I <sub>O</sub> = -12 mA; V <sub>CC</sub> = 2.7 V   | V <sub>CC</sub> - 0.5  | -                  | -                      | V    |
|  |   | I <sub>O</sub> = -18 mA; V <sub>CC</sub> = 3.0 V   | V <sub>CC</sub> - 0.6  | -                  | -                      | V    |
|  |   | I <sub>O</sub> = -24 mA; V <sub>CC</sub> = 3.0 V   | V <sub>CC</sub> - 0.8  | -                  | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage                | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                        |                    |                        |      |
|  |   | I <sub>O</sub> = 100 µA; V <sub>CC</sub> = 1.65 V to 3.6 V                                     | -                      | -                  | 0.2                    | V    |
|  |   | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V  | -                      | -                  | 0.45                   | V    |
|  |   | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V   | -                      | -                  | 0.6                    | V    |
|  |   | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V  | -                      | -                  | 0.4                    | V    |
|  |   | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V  | -                      | -                  | 0.55                   | V    |
| I <sub>I</sub>                             | input leakage current                   | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = 5.5 V or GND   | -                      | ±0.1               | ±5                     | µA   |
| I <sub>CC</sub>                            | supply current                          | V <sub>CC</sub> = 3.6 V; V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0           | -                      | 0.1                | 10                     | µA   |
| ΔI <sub>CC</sub>                           | additional supply current per input pin | V <sub>CC</sub> = 2.7 V to 3.6 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 | -                      | 5                  | 500                    | µA   |
| C <sub>I</sub>                             | input capacitance                       | V <sub>CC</sub> = 0 V to 3.6 V; V <sub>I</sub> = GND to V <sub>CC</sub>                        | -                      | 5.0                | -                      | pF   |
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |   |  |                        |                    |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage                | V <sub>CC</sub> = 1.2 V  | 1.08                   | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.65 × V <sub>CC</sub> | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                    | -                  | -                      | V    |
|  |   | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2.0                    | -                  | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage                 | V <sub>CC</sub> = 1.2 V  | -                      | -                  | 0.12                   | V    |
|  |   | V <sub>CC</sub> = 1.65 V to 1.95 V   | -                      | -                  | 0.35 × V <sub>CC</sub> | V    |
|  |   | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                      | -                  | 0.7                    | V    |
|  |   | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                      | -                  | 0.8                    | V    |

**Table 6: Static characteristics ...continued**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                               | Conditions  | Min             | Typ <sup>[1]</sup> | Max      | Unit    |
|-----------------|---|---|-----------------|--------------------|----------|---------|
| $V_{OH}$        | HIGH-level output voltage               | $V_I = V_{IH}$ or $V_{IL}$                                      |                 |                    |          |         |
|                 |   | $I_O = -100 \mu A; V_{CC} = 1.65 V$ to $3.6 V$                  | $V_{CC} - 0.3$  | -                  | -        | V       |
|                 |   | $I_O = -4 mA; V_{CC} = 1.65 V$                                  | $V_{CC} - 0.6$  | -                  | -        | V       |
|                 |   | $I_O = -8 mA; V_{CC} = 2.3 V$                                   | $V_{CC} - 0.65$ | -                  | -        | V       |
|                 |   | $I_O = -12 mA; V_{CC} = 2.7 V$                                  | $V_{CC} - 0.65$ | -                  | -        | V       |
|                 |   | $I_O = -18 mA; V_{CC} = 3.0 V$                                  | $V_{CC} - 0.75$ | -                  | -        | V       |
| $V_{OL}$        | LOW-level output voltage                | $V_I = V_{IH}$ or $V_{IL}$                                      |                 |                    |          |         |
|                 |   | $I_O = 100 \mu A; V_{CC} = 1.65 V$ to $3.6 V$                   | -               | -                  | 0.3      | V       |
|                 |   | $I_O = 4 mA; V_{CC} = 1.65 V$                                   | -               | -                  | 0.65     | V       |
|                 |   | $I_O = 8 mA; V_{CC} = 2.3 V$                                    | -               | -                  | 0.8      | V       |
|                 |   | $I_O = 12 mA; V_{CC} = 2.7 V$                                   | -               | -                  | 0.6      | V       |
|                 |   | $I_O = 24 mA; V_{CC} = 3.0 V$                                   | -               | -                  | 0.8      | V       |
| $I_I$           | input leakage current                   | $V_{CC} = 3.6 V; V_I = 5.5 V$ or GND                            | -               | -                  | $\pm 20$ | $\mu A$ |
| $I_{CC}$        | supply current                          | $V_{CC} = 3.6 V; V_I = V_{CC}$ or GND; $I_O = 0$                | -               | -                  | 40       | $\mu A$ |
| $\Delta I_{CC}$ | additional supply current per input pin | $V_{CC} = 2.7 V$ to $3.6 V; V_I = V_{CC} - 0.6 V;$<br>$I_O = 0$ | -               | -                  | 5000     | $\mu A$ |

[1] All typical values are measured at  $V_{CC} = 3.3 V$  (unless stated otherwise) and  $T_{amb} = 25^\circ C$ .

## 10. Dynamic characteristics

**Table 7: Dynamic characteristics**Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 7](#).

| Symbol                                    | Parameter   | Conditions                    | Min | Typ <sup>[1]</sup> | Max  | Unit |
|---|---|-------------------------------|-----|--------------------|------|------|
| $T_{amb} = -40^\circ C$ to $+85^\circ C$  |   |                               |     |                    |      |      |
| $t_{PHL}, t_{PLH}$                        | HIGH to LOW, LOW to HIGH propagation delay nA, nB to nY | see <a href="#">Figure 6</a>  |     |                    |      |      |
|   |   | $V_{CC} = 1.2 V$              | -   | 11.0               | -    | ns   |
|   |   | $V_{CC} = 1.65 V$ to $1.95 V$ | 0.5 | 4.1                | 9.0  | ns   |
|   |   | $V_{CC} = 2.3 V$ to $2.7 V$   | 0.9 | 2.4                | 5.1  | ns   |
|   |   | $V_{CC} = 2.7 V$              | 1.0 | 2.5                | 5.5  | ns   |
|   |   | $V_{CC} = 3.0 V$ to $3.6 V$   | 1.0 | 2.2                | 4.6  | ns   |
| $t_{sk(o)}$                               | output skew time  | $V_{CC} = 3.0 V$ to $3.6 V$   | [2] | -                  | 1.0  | ns   |
| $T_{amb} = -40^\circ C$ to $+125^\circ C$ |   |                               |     |                    |      |      |
| $t_{PHL}, t_{PLH}$                        | HIGH to LOW, LOW to HIGH propagation delay nA, nB to nY | see <a href="#">Figure 6</a>  |     |                    |      |      |
|   |   | $V_{CC} = 1.2 V$              | -   | -                  | -    | ns   |
|   |   | $V_{CC} = 1.65 V$             | 0.5 | -                  | 11.5 | ns   |
|   |   | $V_{CC} = 2.3 V$ to $2.7 V$   | 0.9 | -                  | 6.5  | ns   |
|   |   | $V_{CC} = 2.7 V$              | 1.0 | -                  | 7.0  | ns   |
|   |   | $V_{CC} = 3.0 V$ to $3.6 V$   | 1.0 | -                  | 6.0  | ns   |
| $t_{sk(o)}$                               | output skew time  | $V_{CC} = 3.0 V$ to $3.6 V$   | [2] | -                  | 1.5  | ns   |

**Table 7: Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 7](#).

| Symbol                         | Parameter                               | Conditions                              | Min | Typ <sup>[1]</sup> | Max | Unit |
|--------------------------------|---|---|-----|--------------------|-----|------|
| <b>T<sub>amb</sub> = 25 °C</b> |   |   |     |                    |     |      |
| C <sub>PD</sub>                | power dissipation capacitance per gate. | V <sub>I</sub> = GND to V <sub>CC</sub> |     | [3]                |     |      |
|                                |   | V <sub>CC</sub> = 1.65 V to 1.95 V      | -   | 13                 | -   | pF   |
|                                |   | V <sub>CC</sub> = 2.3 V to 2.7 V        | -   | 16                 | -   | pF   |
|                                |   | V <sub>CC</sub> = 3.0 V to 3.6 V        | -   | 20                 | -   | pF   |

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.8 V, 2.5 V, 2.7 V, and 3.3 V respectively.

[2] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

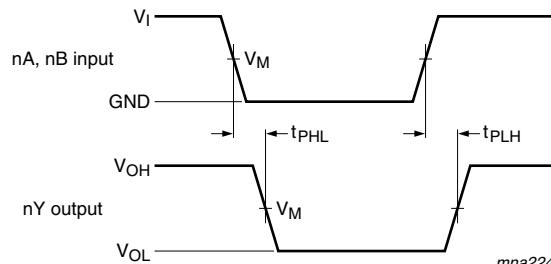
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

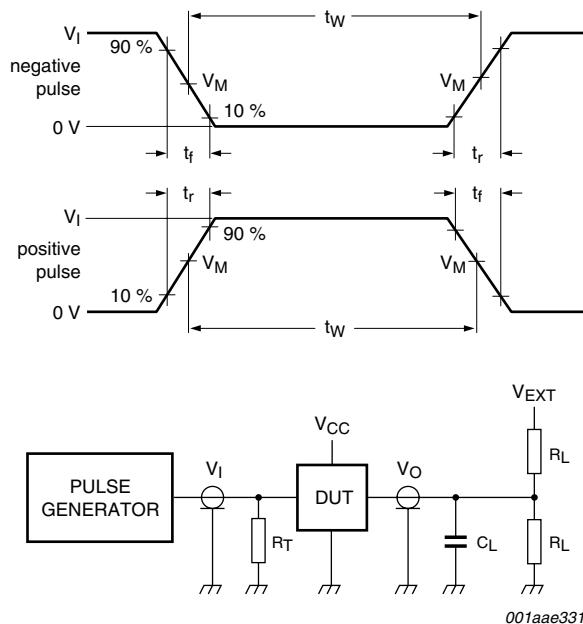
f<sub>i</sub> = input frequency in MHz,f<sub>o</sub> = output frequency in MHz,C<sub>L</sub> = output load capacitance in pF,V<sub>CC</sub> = supply voltage in Volts,

N = number of inputs switching,

Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs.

## 11. AC waveforms

V<sub>M</sub> = 1.5 V at V<sub>CC</sub> ≥ 2.7 V;V<sub>M</sub> = 0.5 × V<sub>CC</sub> at V<sub>CC</sub> < 2.7 V;V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage drops that occur with the output load.**Fig 6. The inputs nA and nB to output nY propagation delay**



Test data is given in [Table 8](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig 7. Load circuitry for switching times**

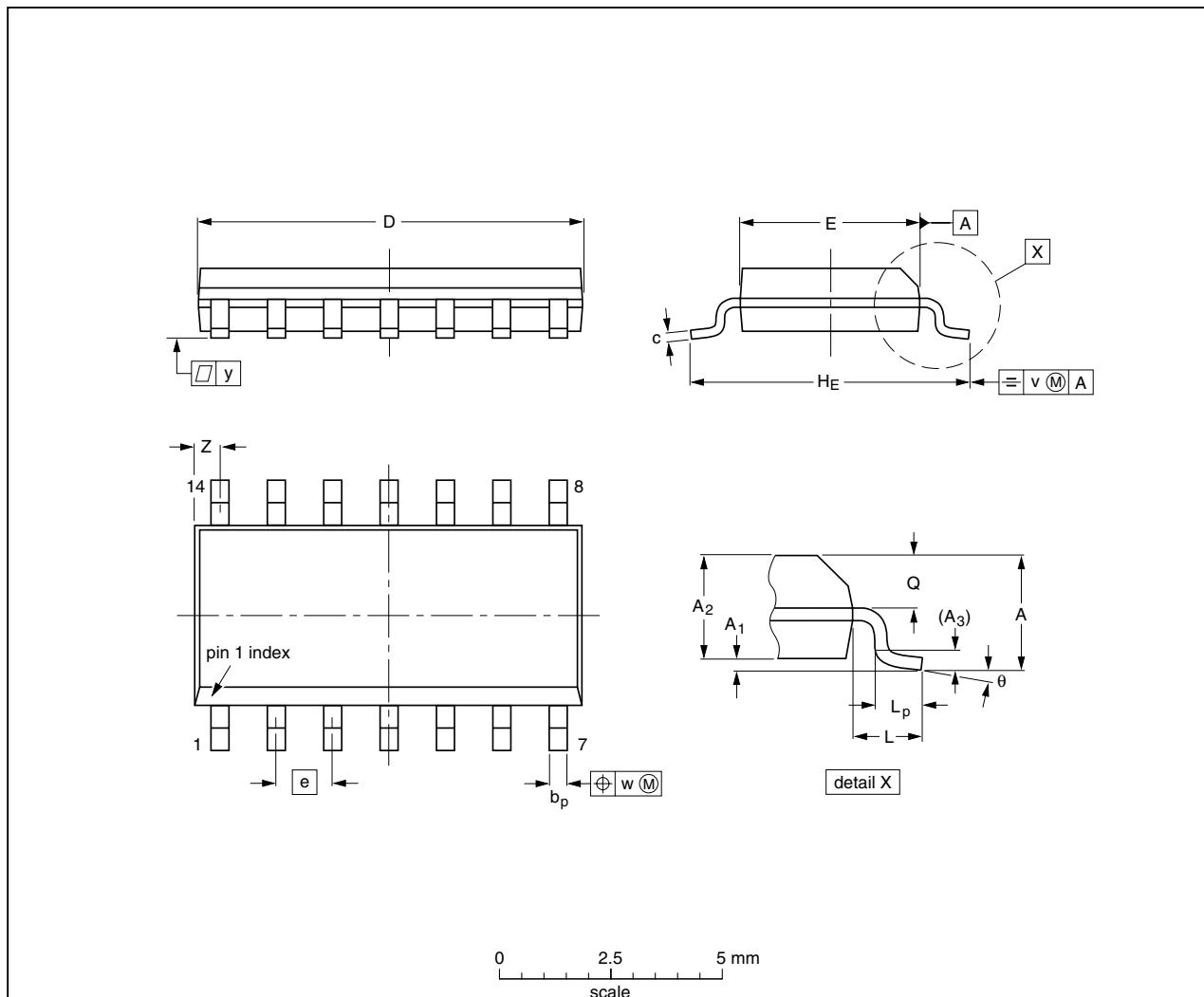
**Table 8: Test data**

| Supply voltage   | Input    |               | Load  |              | $V_{EXT}$          |                    |                    |
|------------------|----------|---------------|-------|--------------|--------------------|--------------------|--------------------|
|                  | $V_I$    | $t_r, t_f$    | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ | $t_{PLZ}, t_{PZL}$ | $t_{PHZ}, t_{PZH}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2$ ns   | 30 pF | 1 k $\Omega$ | open               | $2 \times V_{CC}$  | GND                |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2$ ns   | 30 pF | 500 $\Omega$ | open               | $2 \times V_{CC}$  | GND                |
| 2.7 V            | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | 6 V                | GND                |
| 3.0 V to 3.6 V   | 2.7 V    | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               | 6 V                | GND                |

## 12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT   | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | A <sub>3</sub> | b <sub>p</sub> | c                | D <sup>(1)</sup> | E <sup>(1)</sup> | e    | H <sub>E</sub> | L     | L <sub>p</sub> | Q              | v    | w    | y     | z <sup>(1)</sup> | θ  |
|--------|-----------|----------------|----------------|----------------|----------------|------------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm     | 1.75      | 0.25<br>0.10   | 1.45<br>1.25   | 0.25           | 0.49<br>0.36   | 0.25<br>0.19     | 8.75<br>8.55     | 4.0<br>3.8       | 1.27 | 6.2<br>5.8     | 1.05  | 1.0<br>0.4     | 0.7<br>0.6     | 0.25 | 0.25 | 0.1   | 0.7<br>0.3       | 8° |
| inches | 0.069     | 0.010<br>0.004 | 0.057<br>0.049 | 0.01           | 0.019<br>0.014 | 0.0100<br>0.0075 | 0.35<br>0.34     | 0.16<br>0.15     | 0.05 | 0.244<br>0.228 | 0.041 | 0.039<br>0.016 | 0.028<br>0.024 | 0.01 | 0.01 | 0.004 | 0.028<br>0.012   | 0° |

**Note**

- Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE VERSION | REFERENCES |        |       |  | EUROPEAN PROJECTION | ISSUE DATE        |
|-----------------|------------|--------|-------|--|---------------------|-------------------|
|                 | IEC        | JEDEC  | JEITA |  |                     |                   |
| SOT108-1        | 076E06     | MS-012 |       |  |                     | 99-12-27-03-02-19 |

**Fig 8. Package outline SOT108-1 (SO14)**

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

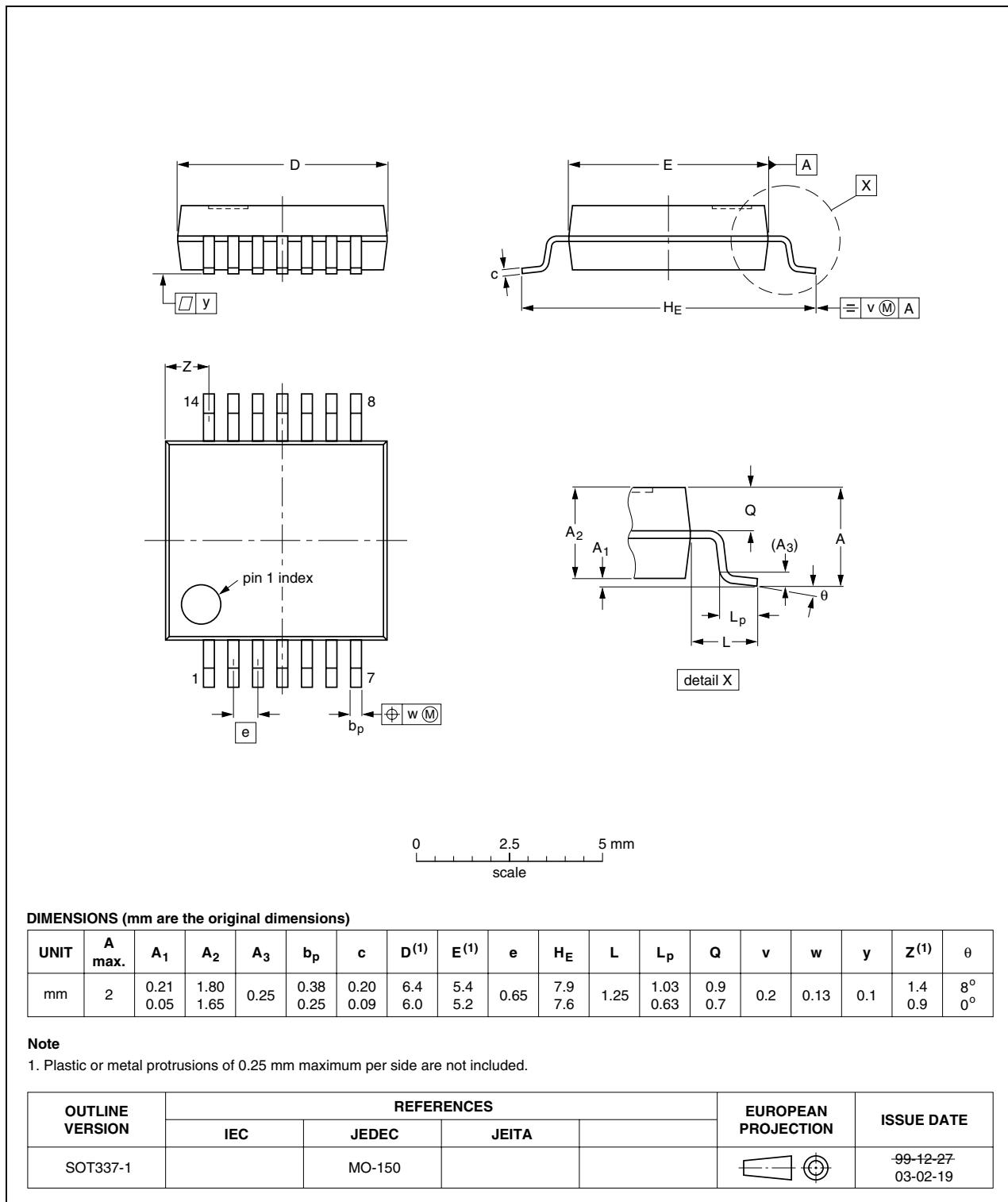


Fig 9. Package outline SOT337-1 (SSOP14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

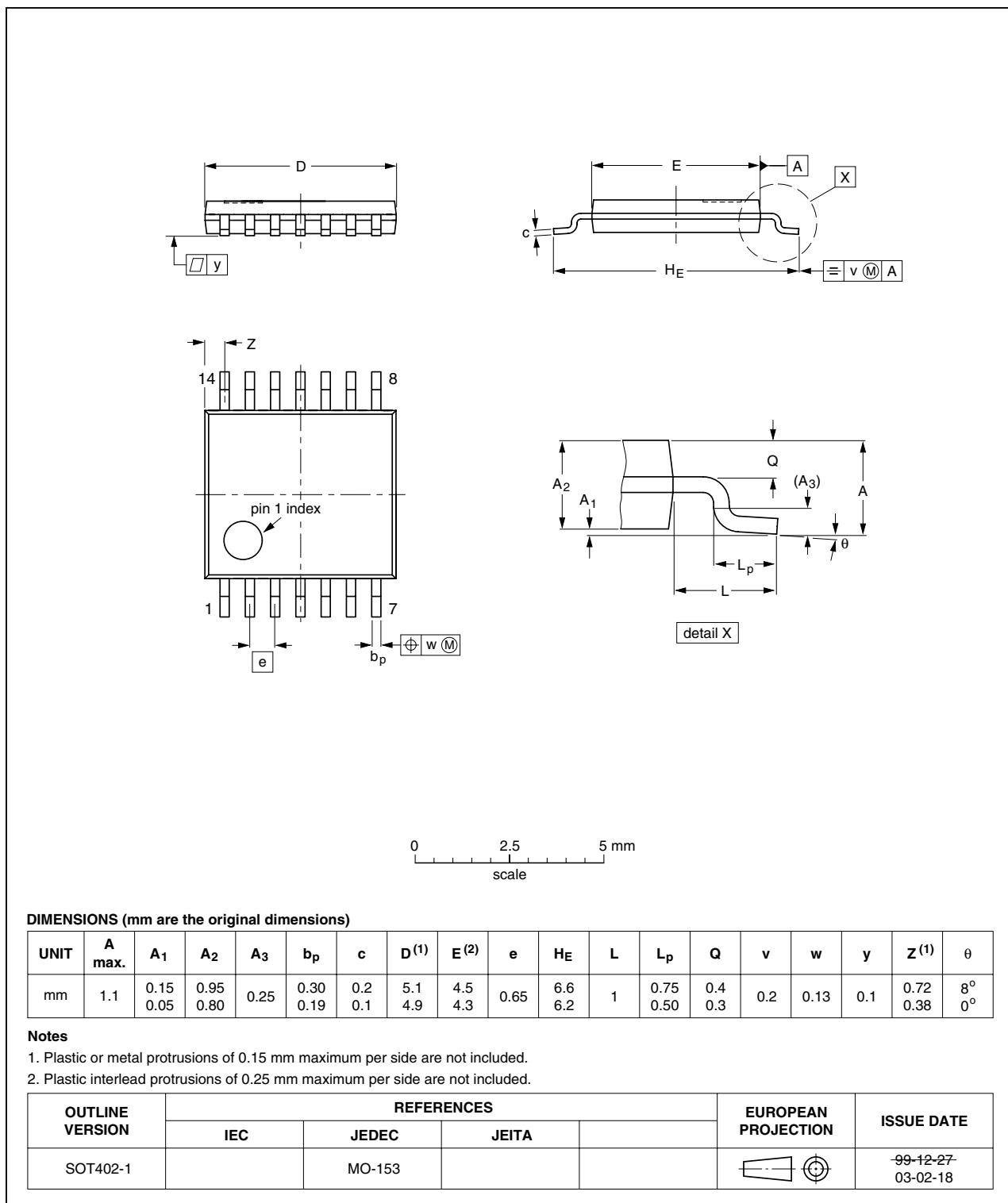


Fig 10. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads;  
14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1

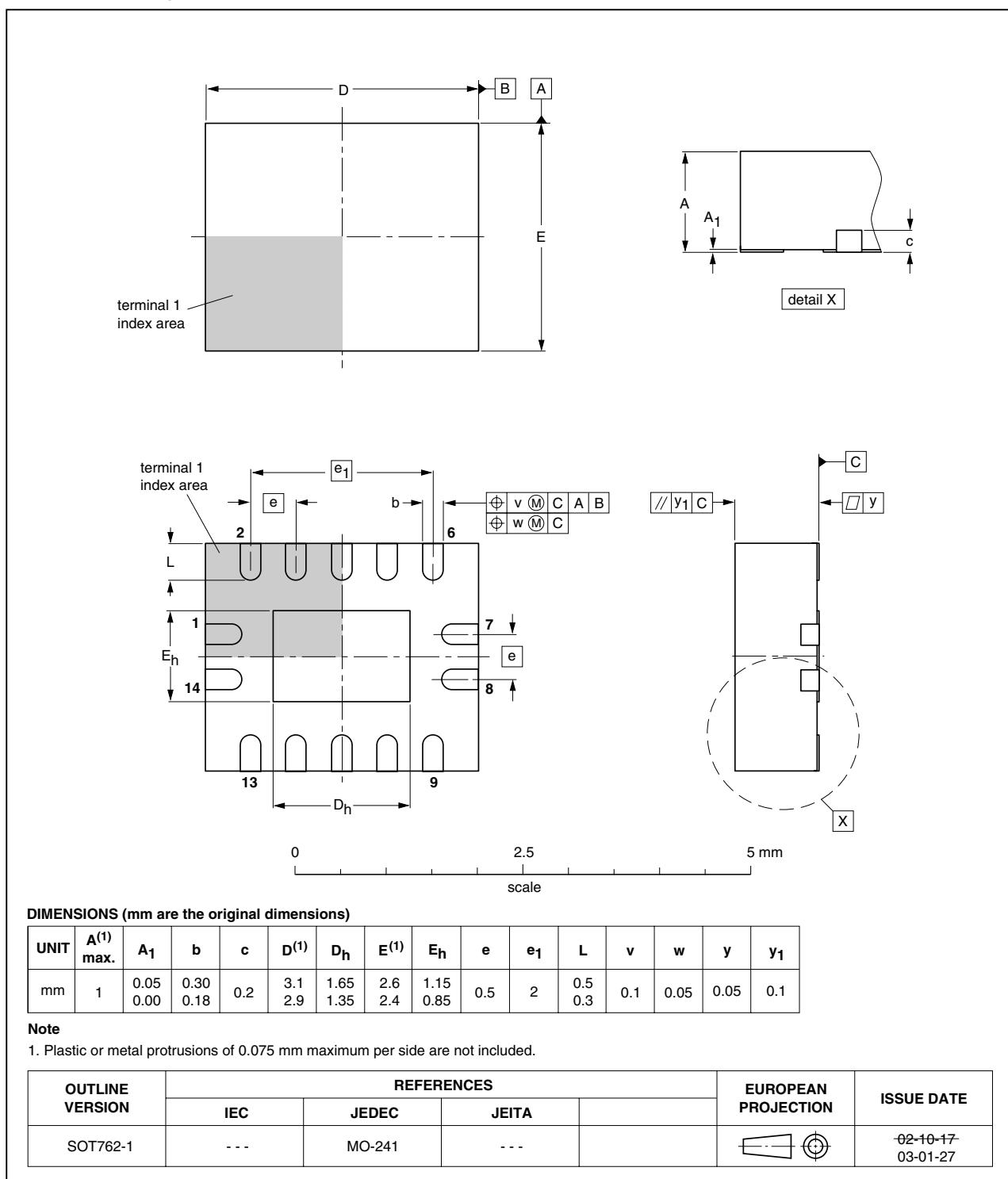


Fig 11. Package outline SOT762-1 (DHVQFN14)

## 13. Abbreviations

**Table 9. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| TTL     | Transistor Transistor Logic             |

## 14. Revision history

**Table 10. Revision history**

| Document ID                     | Release date | Data sheet status     | Change notice | Supersedes  |
|---------------------------------|--------------|-----------------------|---------------|---|
| 74LVC86A_5<br>Modifications:    | <tbd>        | Product data sheet    | -             | 74LVC86A_4  |
|                                 |              |                       |               | <ul style="list-style-type: none"> <li>• The format of this data sheet is redesigned to comply with the current presentation and information standard of Philips Semiconductors.</li> <li>• <a href="#">Table 4</a>, <a href="#">Table 5</a>, <a href="#">Table 6</a>, <a href="#">Table 7</a> and <a href="#">Table 8</a>: values added for lower voltage ranges.</li> </ul> |
| 74LVC86A_4<br>(9397 750 129666) | 20040304     | Product specification | -             | 74LVC86A_3  |
| 74LVC86A_3<br>(9397 750 10503)  | 20031111     | Product specification | -             | 74LVC86A_2  |
| 74LVC86A_2<br>(9397 750 04488)  | 19980428     | Product specification | -             | 74LVC86A_1  |
| 74LVC86A_1                      | -            | -                     | -             | -   |

## 15. Legal information

### 15.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.semiconductors.philips.com>.

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